

# Manipulating Edge Channel Transport in Graphene

Master project and thesis

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# Structure

- Introduction
- Theory (SGM and backscattering)
- Results
- Conclusions
- Discussion

# Structure

Not discussed

- Quantum Hall effect
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## Not discussed

- Quantum Hall effect
- Edge reconstruction
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## Not discussed

- Quantum Hall effect
- Edge reconstruction
- Fabrication
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- Quantum Hall effect
- Edge reconstruction
- Fabrication
- Multi-ribbon devices (effect of ribbon width on transport)
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## Not discussed

- Quantum Hall effect
- Edge reconstruction
- Fabrication
- Multi-ribbon devices (effect of ribbon width on transport)
- Hysteresis

## Traineeship program

- To fabricate and characterize graphene nanoribbons by low temperature magneto-transport measurements
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## Traineeship program

- To fabricate and characterize graphene nanoribbons by low temperature magneto-transport measurements
- The quantum Hall regime will be explored, as part of the research program to develop understanding of edge channel physics in graphene

# Introduction

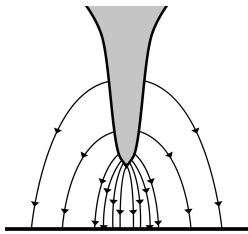
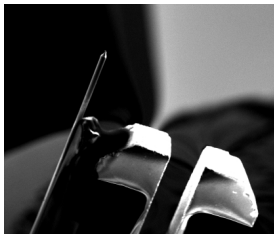
## Internship goal

- To manipulate edge channel transport with the Scanning Gate Microscope (SGM)

# Theory

## Scanning Gate Microscopy

- AFM
- 300 mK
- 8 T

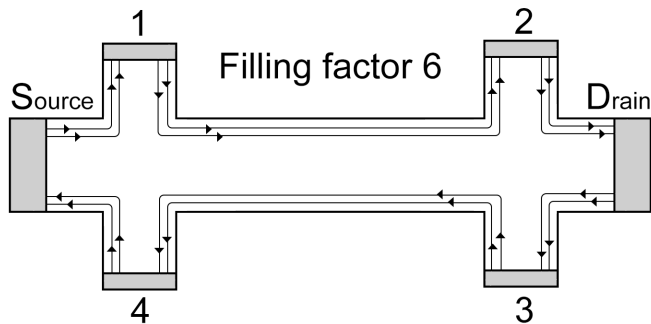


# Theory

## Backscattering edge channels

- $R_{xx} = 0 \text{ k}\Omega$
- $R_{14} = \frac{h}{e^2} \frac{1}{6} \approx 4.3 \text{ k}\Omega$

$$R_{23} = \frac{h}{e^2} \frac{1}{6} \approx 4.3 \text{ k}\Omega$$



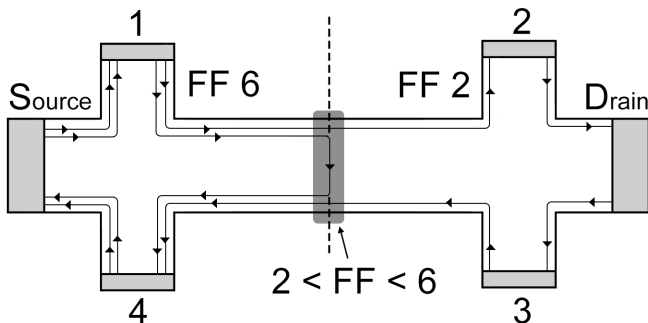
# Theory

## Backscattering edge channels

- $R_{xx} = 0 \text{ k}\Omega$

- $R_{14} = \frac{h}{e^2} \frac{1}{6} \approx 4.3 \text{ k}\Omega$

$$R_{23} = \frac{h}{e^2} \frac{1}{2} \approx 12.9 \text{ k}\Omega$$



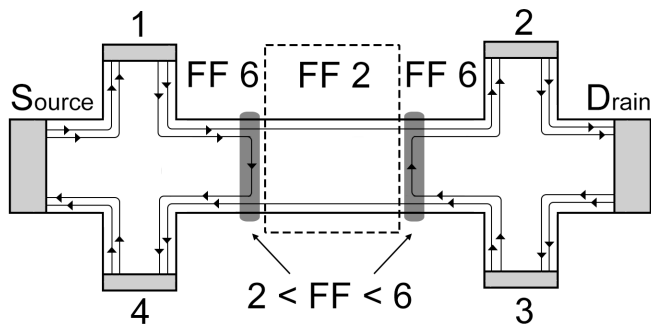
# Theory

## Backscattering edge channels

- $R_{xx} = 8.6 \text{ k}\Omega$

- $R_{14} = \frac{h}{e^2} \frac{1}{6} \approx 4.3 \text{ k}\Omega$

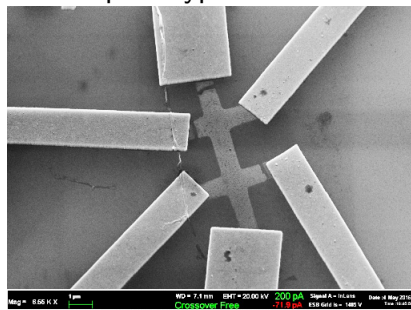
$$R_{23} = \frac{h}{e^2} \frac{1}{6} \approx 4.3 \text{ k}\Omega$$



# Results

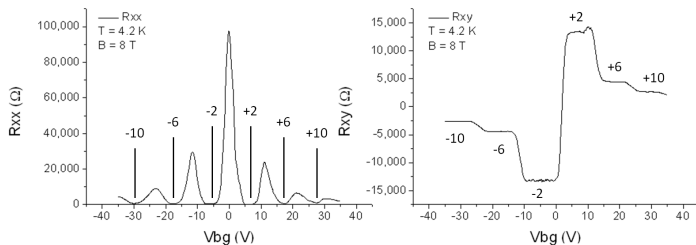
Ribbon dimensions:  $L \approx 6 \mu\text{m}$ ,  $W \approx 800 \text{ nm}$

prototype device



# Results

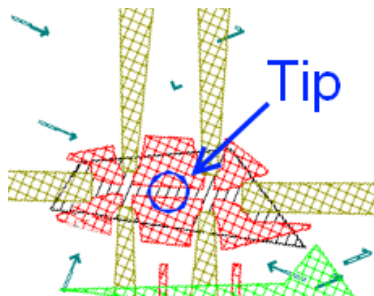
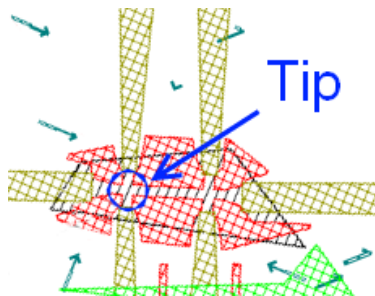
## Quantum Hall effect





# Results

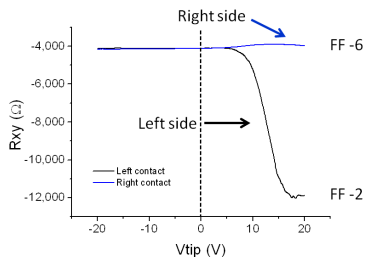
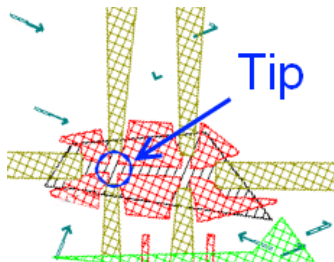
Tip position (static)



# Results

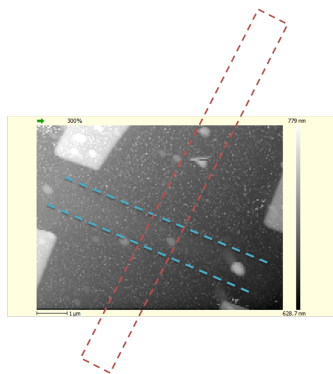
## Local control over the filling factor

$T = 4.2$  K,  $B = 8$  T



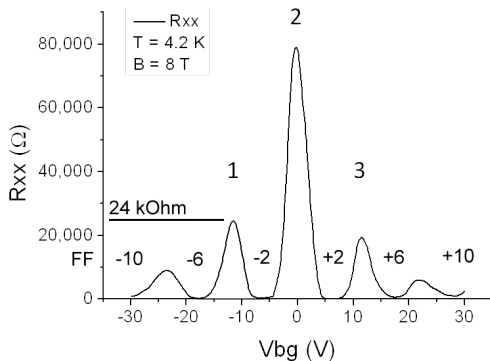
# Results

## Scanning the tip



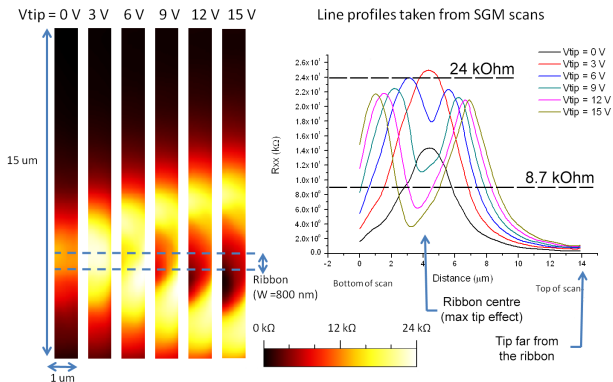
# Results

## Scanning the tip



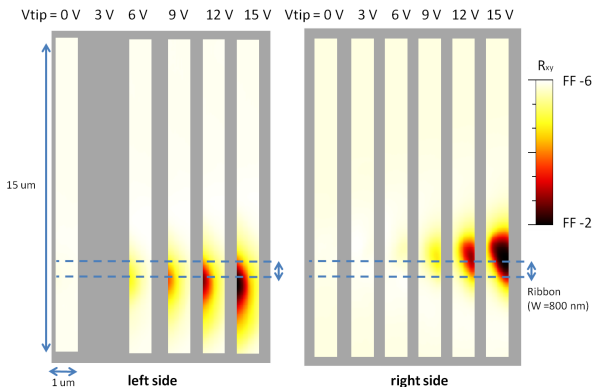
# Results

## Scanning the tip: $R_{xx}$



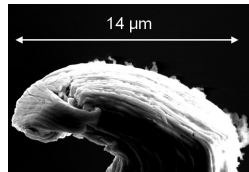
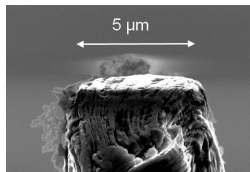
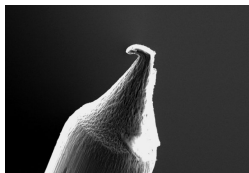
# Results

## Scanning the tip: $R_{xy}$



# Results

## Tip shape



# Conclusion

- A local control over the filling factor achieved
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# Conclusion

- A local control over the filling factor achieved
- Tip was too large to determine edge channel structure

# Discussion

- Discussion